

APPLICATIONS

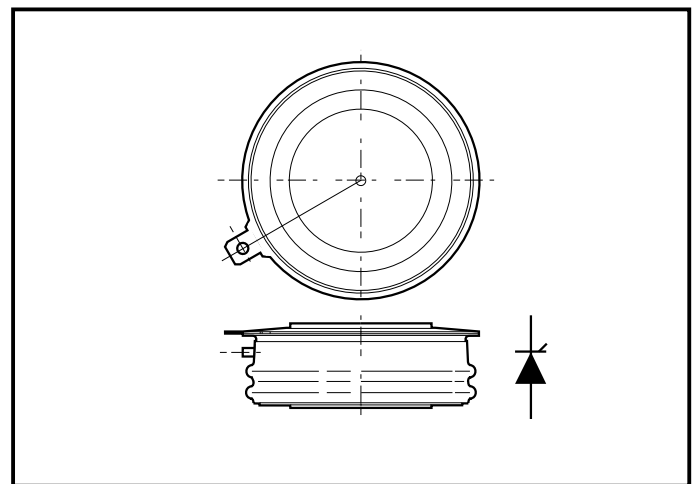
- Variable speed A.C. motor drive inverters (VSD-AC)
- Uninterruptable Power Supplies
- High Voltage Converters
- Choppers
- Welding
- Induction Heating
- DC/DC Converters

KEY PARAMETERS

I_{TCM}	700A
V_{DRM}	1300V
$I_{T(AV)}$	250A
dV_D/dt	500V/ μ s
di_T/dt	500A/ μ s

FEATURES

- Double Side Cooling
- High Reliability In Service
- High Voltage Capability
- Fault Protection Without Fuses
- High Surge Current Capability
- Turn-off Capability Allows Reduction In Equipment Size And Weight. Low Noise Emission Reduces Acoustic Cladding Necessary For Environmental Requirements



Outline type code: E.
See Package Details for further information.

VOLTAGE RATINGS

Type Number	Repetitive Peak Off-state Voltage V_{DRM}	Repetitive Peak Reverse Voltage V_{RRM}	Conditions
DGT304SE13	1300	16	$T_{vj} = 125^{\circ}\text{C}$, $I_{DM} = 50\text{mA}$, $I_{RRM} = 50\text{mA}$, $V_{RG} = 2\text{V}$

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{TCM}	Repetitive peak controllable on-state current	$V_D = 60\%V_{DRM}$, $T_j = 125^{\circ}\text{C}$, $di_{GQ}/dt = 15\text{A}/\mu\text{s}$, $C_s = 2.0\mu\text{F}$	700	A
$I_{T(AV)}$	Mean on-state current	$T_{HS} = 80^{\circ}\text{C}$. Double side cooled. Half sine 50Hz.	250	A
$I_{T(RMS)}$	RMS on-state current	$T_{HS} = 80^{\circ}\text{C}$. Double side cooled. Half sine 50Hz.	390	A

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine. $T_J = 125^\circ\text{C}$	4.0	kA
I^2t	I^2t for fusing	10ms half sine. $T_J = 125^\circ\text{C}$	80000	A^2s
di_T/dt	Critical rate of rise of on-state current	$V_D = 60\% V_{DRM}$, $I_T = 700\text{A}$, $T_J = 125^\circ\text{C}$, $I_{FG} > 20\text{A}$, Rise time $< 1.0\mu\text{s}$	500	$\text{A}/\mu\text{s}$
dV_D/dt	Rate of rise of off-state voltage	To 80% V_{DRM} ; $R_{GK} \leq 1.5\Omega$, $T_J = 125^\circ\text{C}$	500	$\text{V}/\mu\text{s}$

GATE RATINGS

Symbol	Parameter	Conditions	Min.	Max.	Units
V_{RGM}	Peak reverse gate voltage	This value maybe exceeded during turn-off	-	16	V
I_{FGM}	Peak forward gate current		-	50	A
$P_{FG(AV)}$	Average forward gate power		-	10	W
P_{RGM}	Peak reverse gate power		-	6	kW
di_{GQ}/dt	Rate of rise of reverse gate current		10	50	$\text{A}/\mu\text{s}$
$t_{ON(min)}$	Minimum permissible on time		20	-	μs
$t_{OFF(min)}$	Minimum permissible off time		40	-	μs

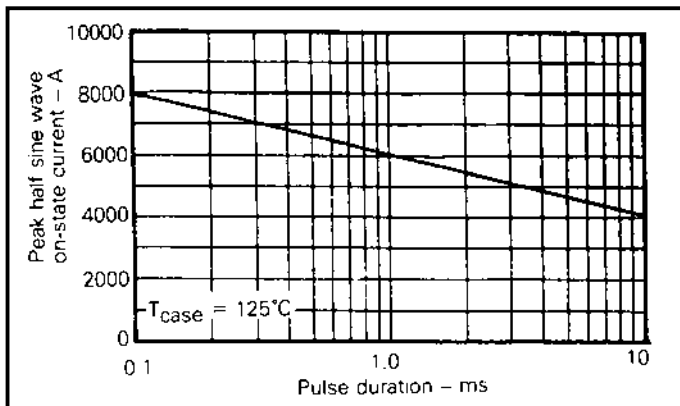
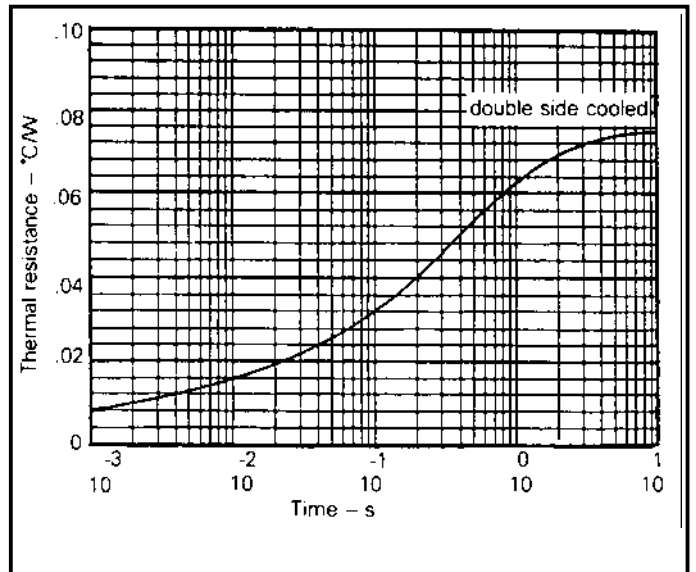
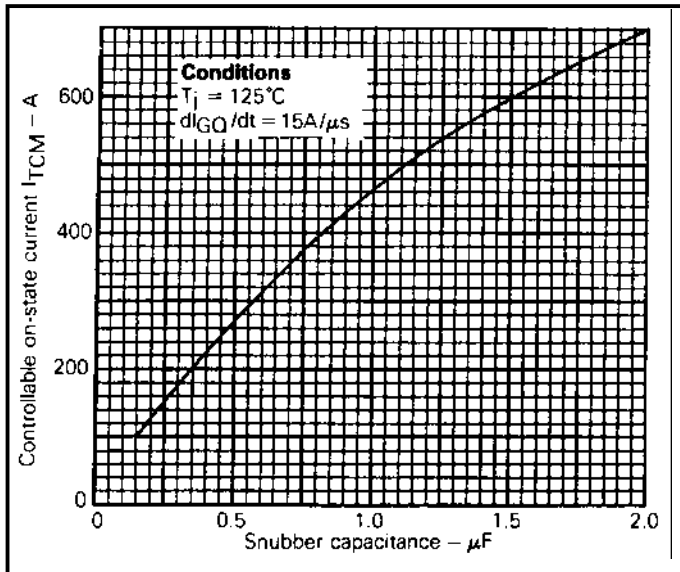
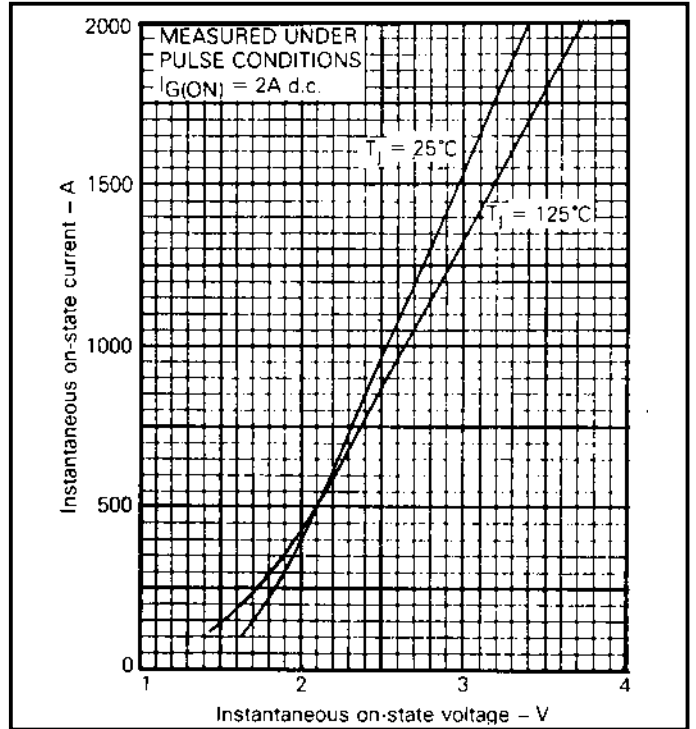
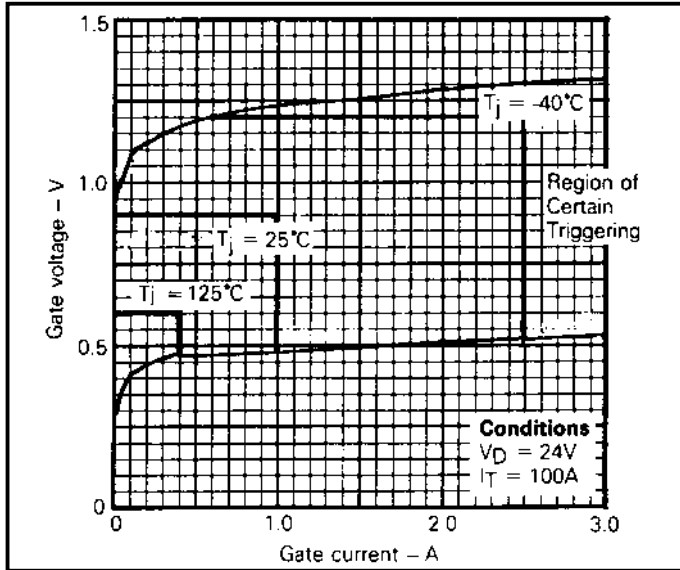
THERMAL RATINGS

Symbol	Parameter	Conditions	Min.	Max.	Units	
$R_{th(j-hs)}$	DC thermal resistance - junction to heatsink surface	Double side cooled	-	0.075	$^\circ\text{C}/\text{W}$	
		Anode side cooled	-	0.12	$^\circ\text{C}/\text{W}$	
		Cathode side cooled	-	0.20	$^\circ\text{C}/\text{W}$	
$R_{th(c-hs)}$	Contact thermal resistance	Clamping force 5.5kN With mounting compound	per contact	-	0.018	$^\circ\text{C}/\text{W}$
T_{vj}	Virtual junction temperature		-	125	$^\circ\text{C}$	
T_{OP}/T_{stg}	Operating junction/storage temperature range		-40	125	$^\circ\text{C}$	
-	Clamping force		5.0	6.0	kN	

CHARACTERISTICS

T_j = 125°C unless stated otherwise					
Symbol	Parameter	Conditions	Min.	Max.	Units
V _{TM}	On-state voltage	At 600A peak, I _{G(ON)} = 2A d.c.	-	2.2	V
I _{DM}	Peak off-state current	At = V _{DRM} , V _{RG} = 2V	-	25	mA
I _{RRM}	Peak reverse current	At V _{RRM}	-	50	mA
V _{GT}	Gate trigger voltage	V _D = 24V, I _T = 100A, T _j = 25°C	-	0.9	V
I _{GT}	Gate trigger current	V _D = 24V, I _T = 100A, T _j = 25°C	-	1.0	A
I _{RGM}	Reverse gate cathode current	V _{RGM} = 16V, No gate/cathode resistor	-	50	mA
E _{ON}	Turn-on energy	V _D = 900V, I _T = 600A, di _T /dt = 300A/μs	-	130	mJ
t _d	Delay time	I _{FG} = 20A, rise time < 1.0μs	-	1.5	μs
t _r	Rise time	R _L = (Residual inductance 3μH)	-	3.0	μs
E _{OFF}	Turn-off energy	I _T = 600A, V _{DM} = 750V Snubber Cap Cs = 1.5μF, di _{GQ} /dt = 15A/μs R _L = (Residual inductance 3μH)	-	350	mJ
t _{tail}	Tail time		-	10	μs
t _{gs}	Storage time		-	11	μs
t _{gf}	Fall time		-	0.9	μs
t _{gq}	Gate controlled turn-off time		-	11.9	μs
Q _{GQ}	Turn-off gate charge		-	700	μC
Q _{GQT}	Total turn-off gate charge		-	1400	μC

CURVES



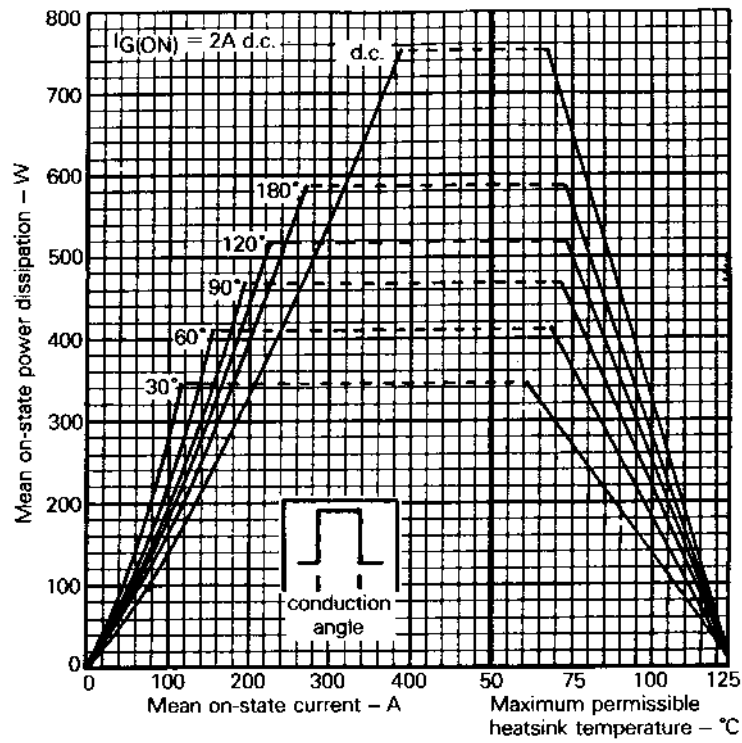


Fig.6 Steady state rectangular wave conduction loss - double side cooled

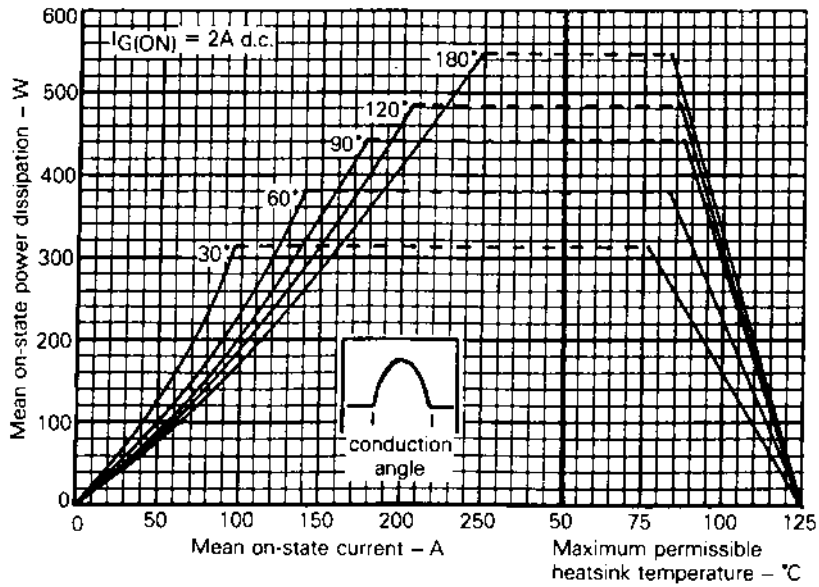


Fig.7 Steady state sinusoidal wave conduction loss - double side cooled

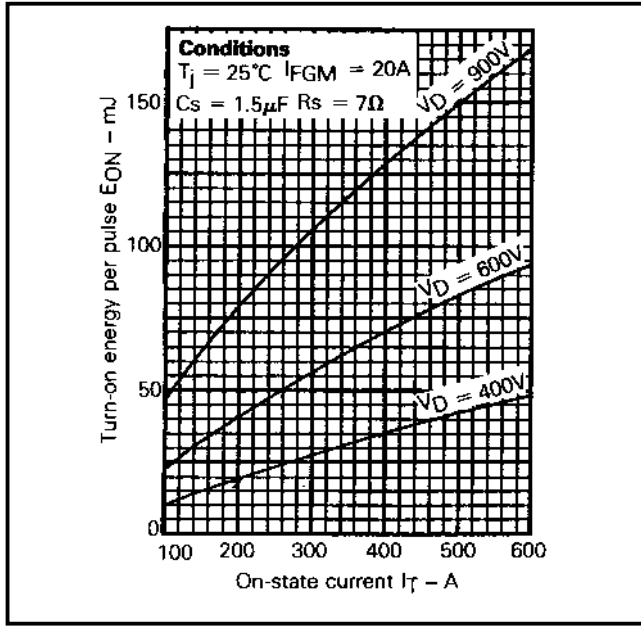


Fig.8 Turn-on energy vs on-state current

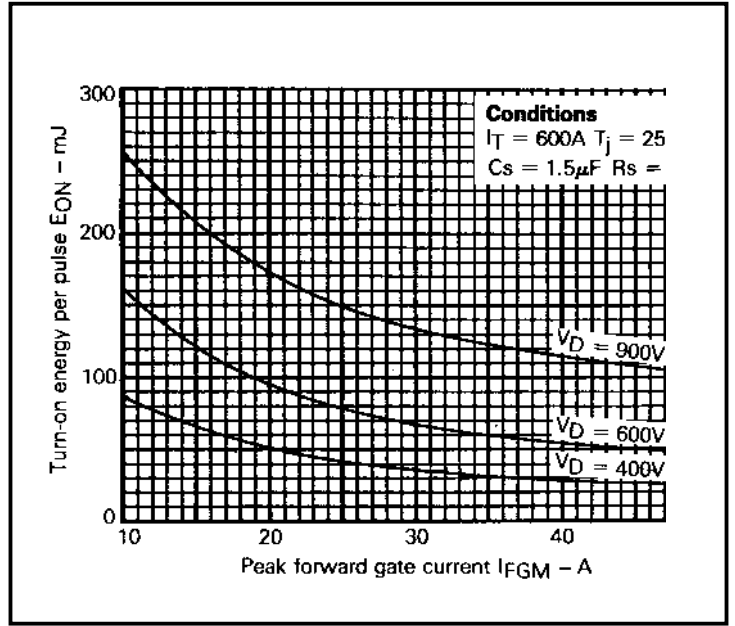


Fig.9 Turn-on energy vs peak forward gate current

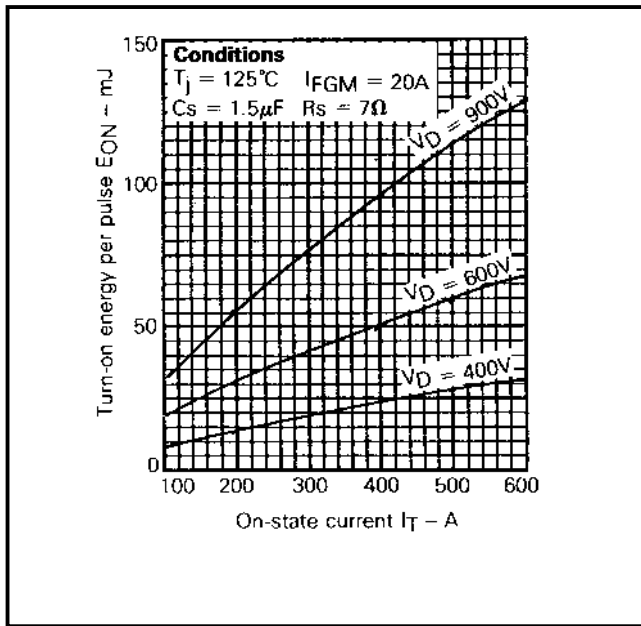


Fig.10 Turn-on energy vs on-state current

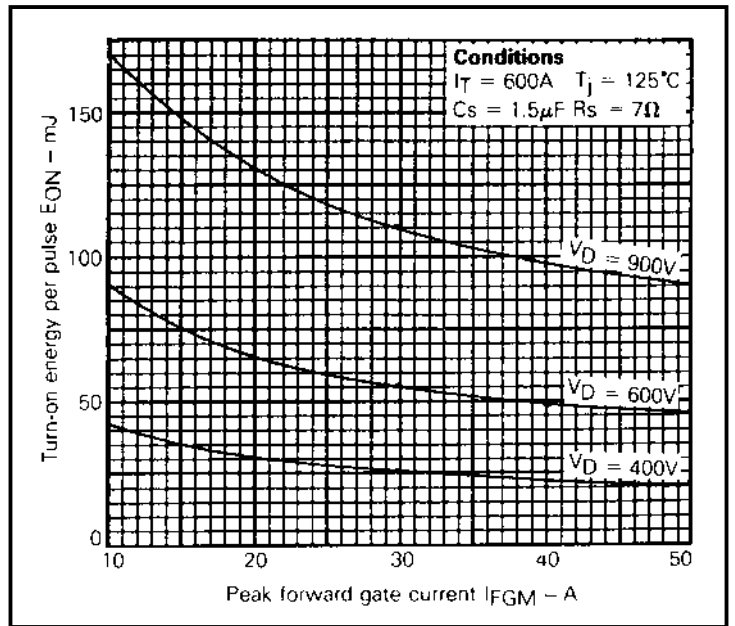


Fig.11 Turn-on energy vs peak forward gate current

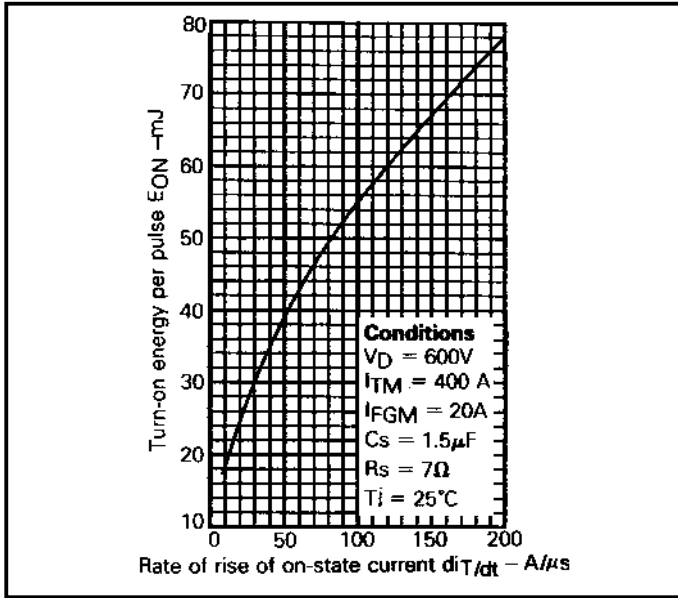


Fig.12 Turn-on energy vs rate of rise of on-state current

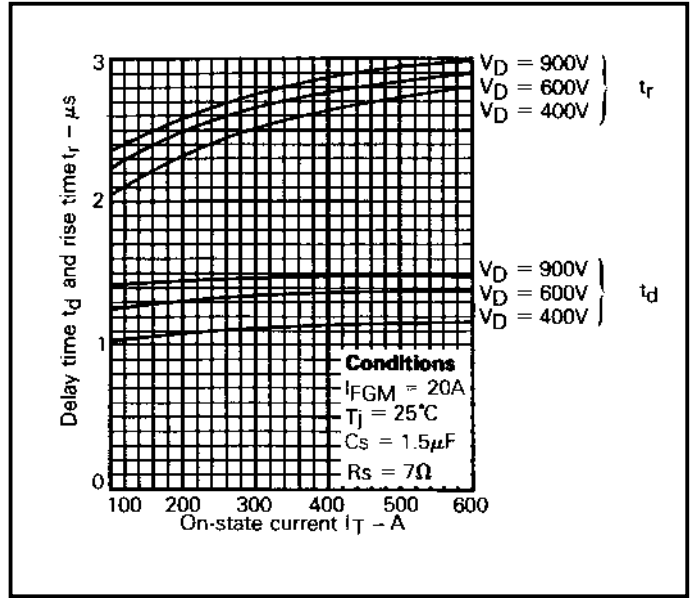


Fig.13 Delay time and rise time vs on-state current

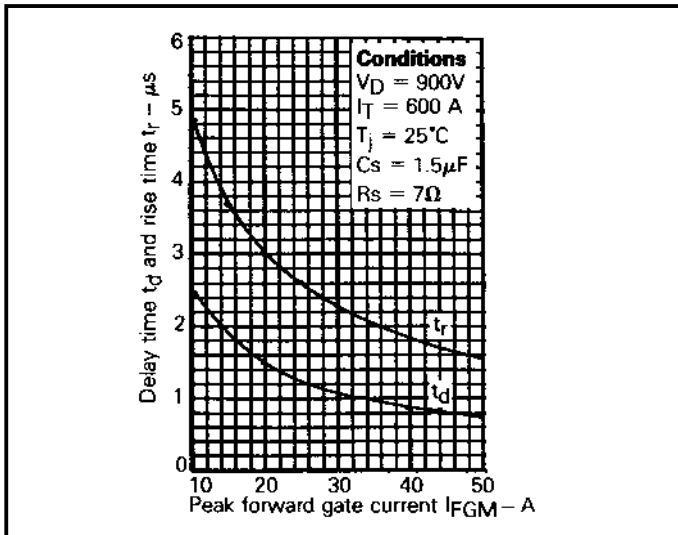


Fig.14 Delay time and rise time vs peak forward gate current

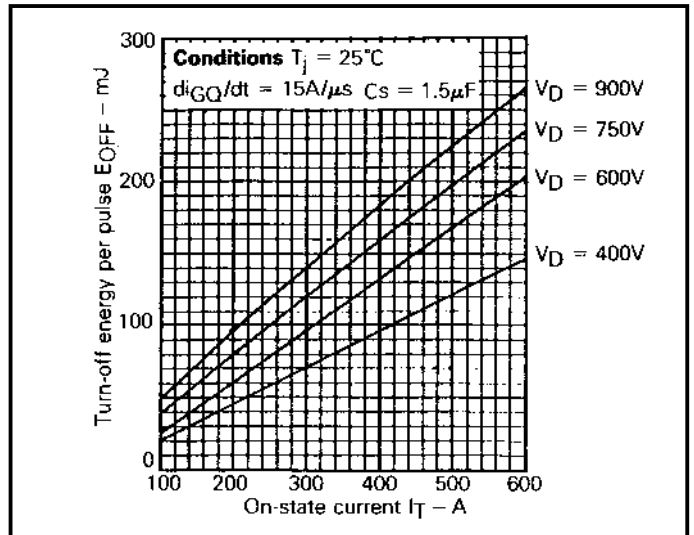


Fig.15 Turn-off energy vs on-state current

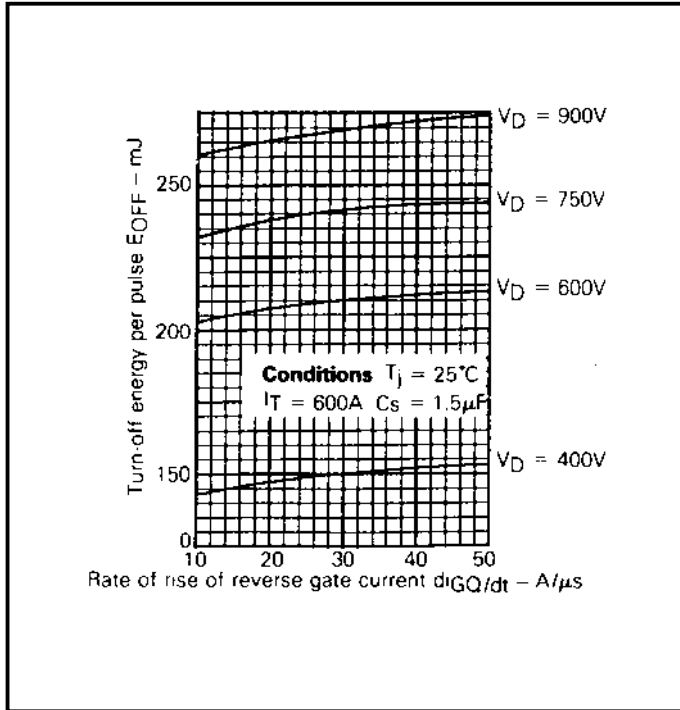


Fig.16 Turn-off energy vs rate of rise of reverse gate current

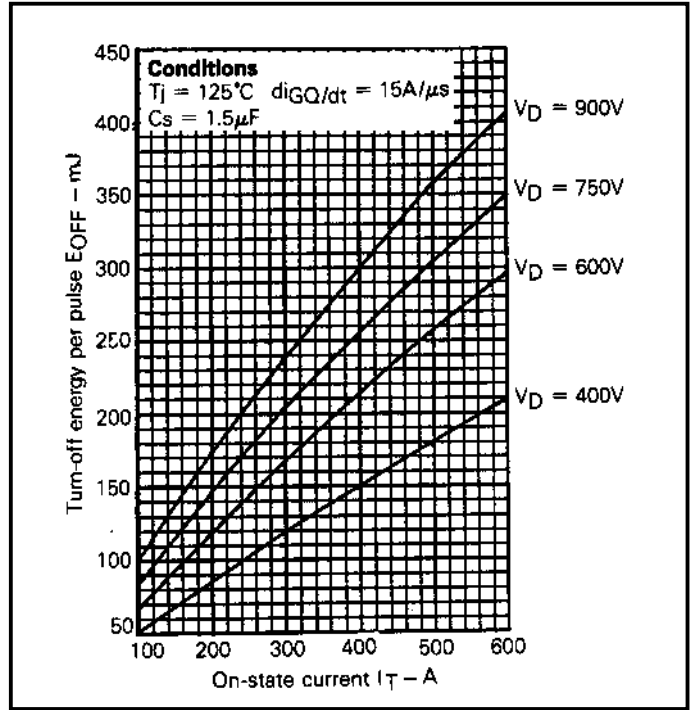


Fig.17 Turn-off energy vs on-state current

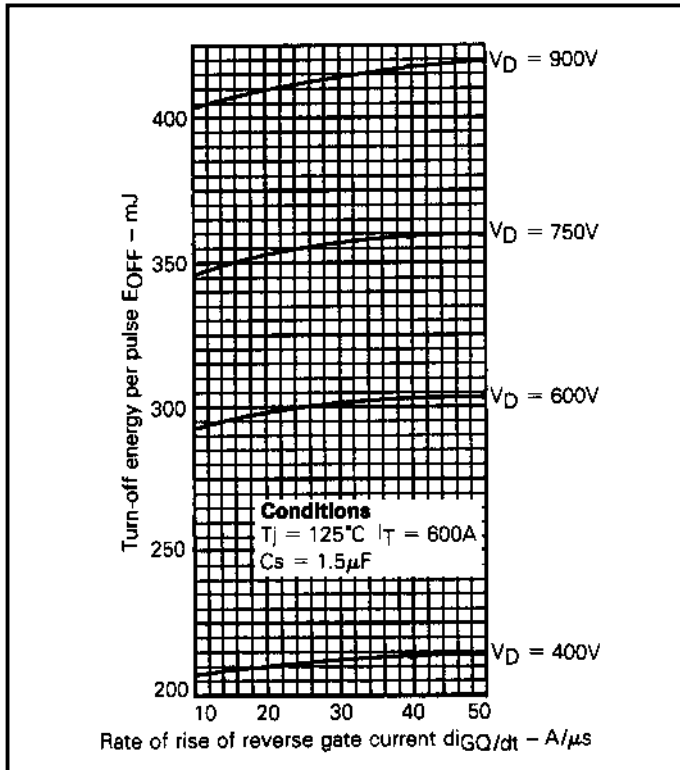


Fig.18 Turn-off energy vs rate of rise of reverse gate current

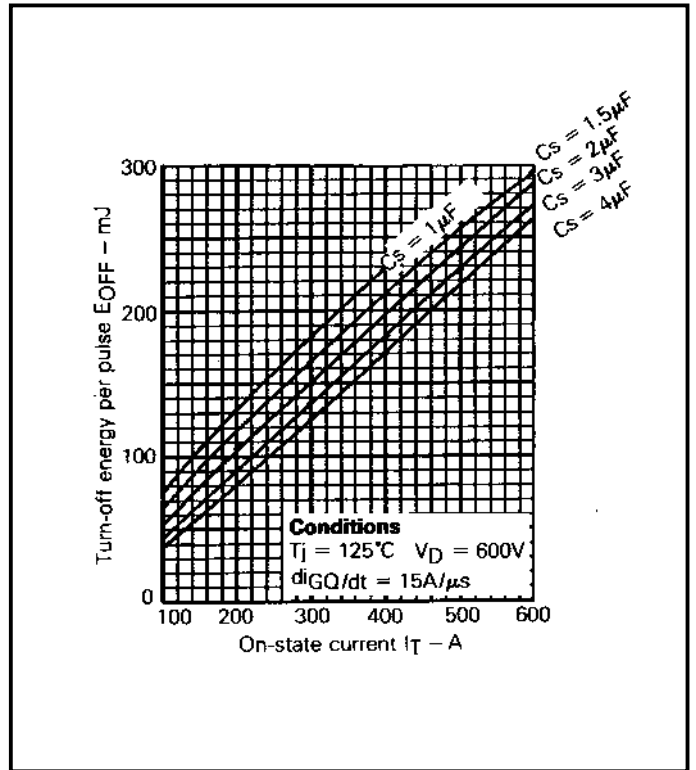


Fig.19 Turn-off energy vs on-state current with C_s as parameter

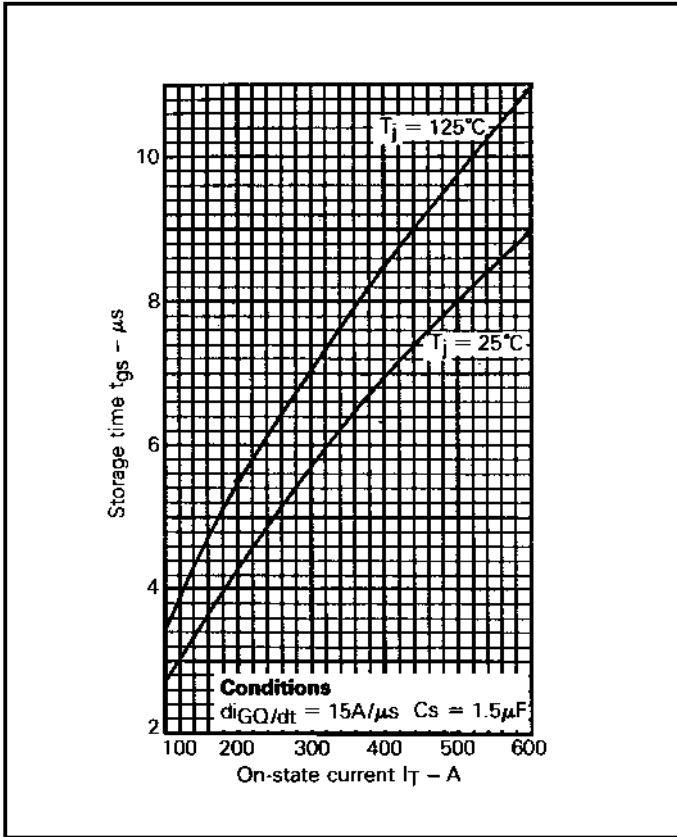


Fig.20 Storage time vs on-state current

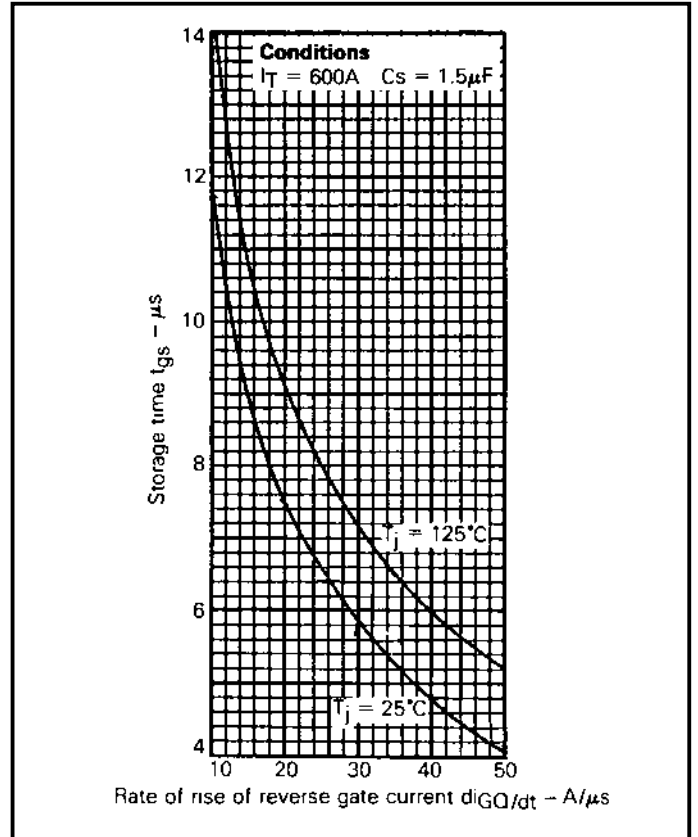


Fig.21 Storage time vs rate of rise of reverse gate current

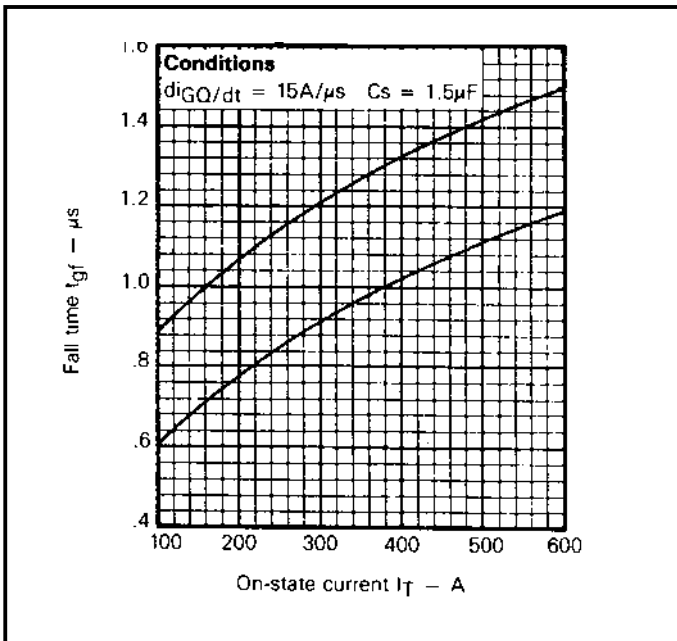


Fig.22 Fall time vs on-state current

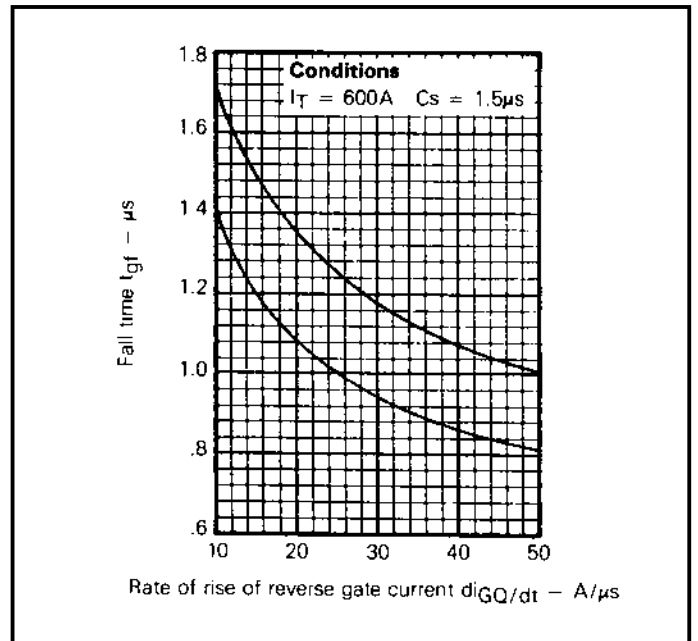
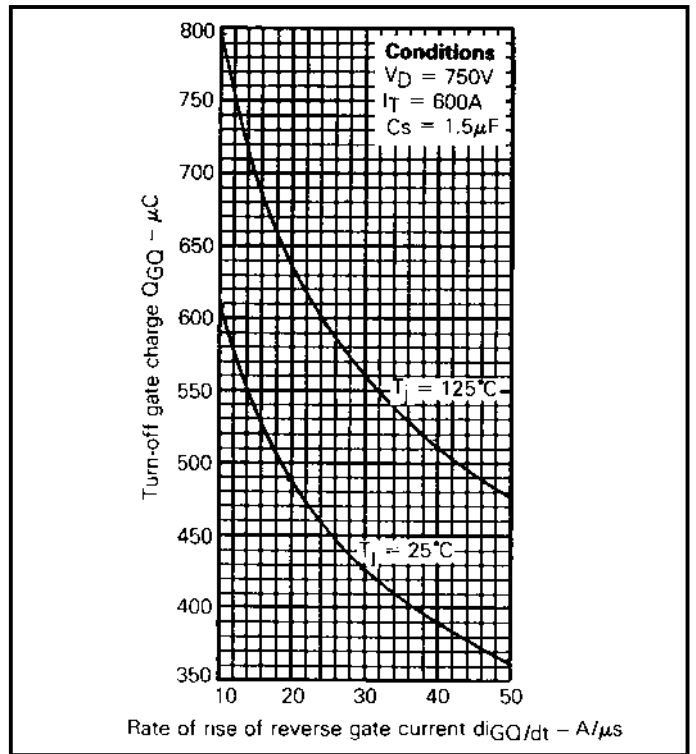
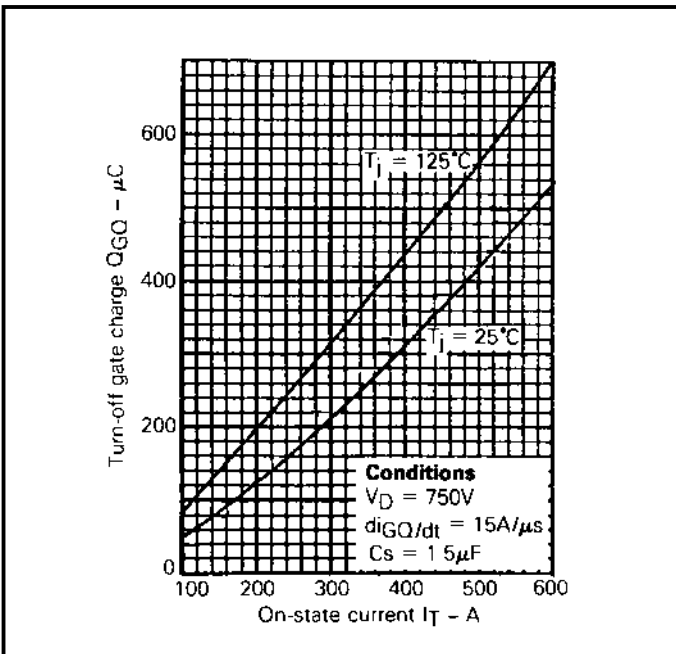
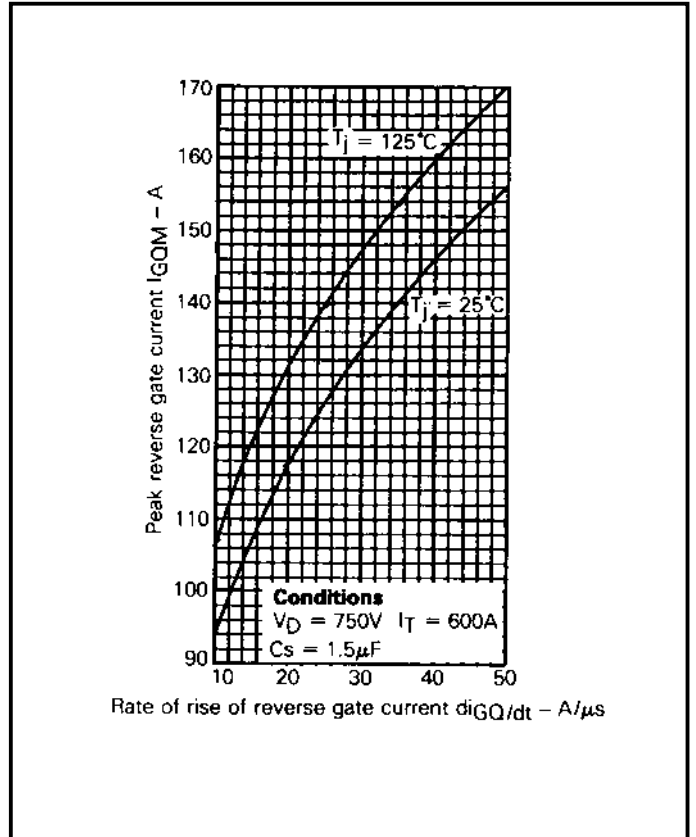
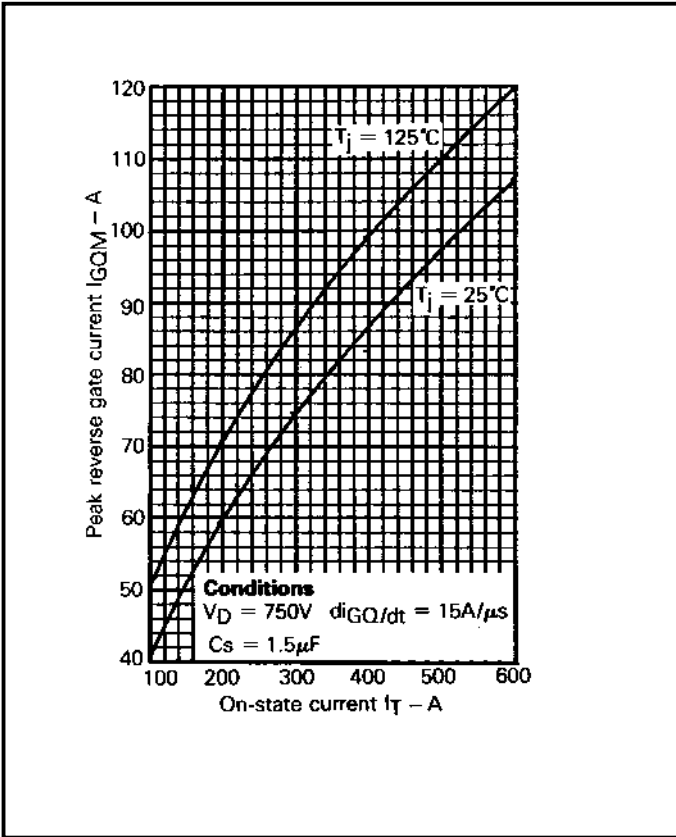


Fig.23 Fall time vs rate of rise of reverse gate current



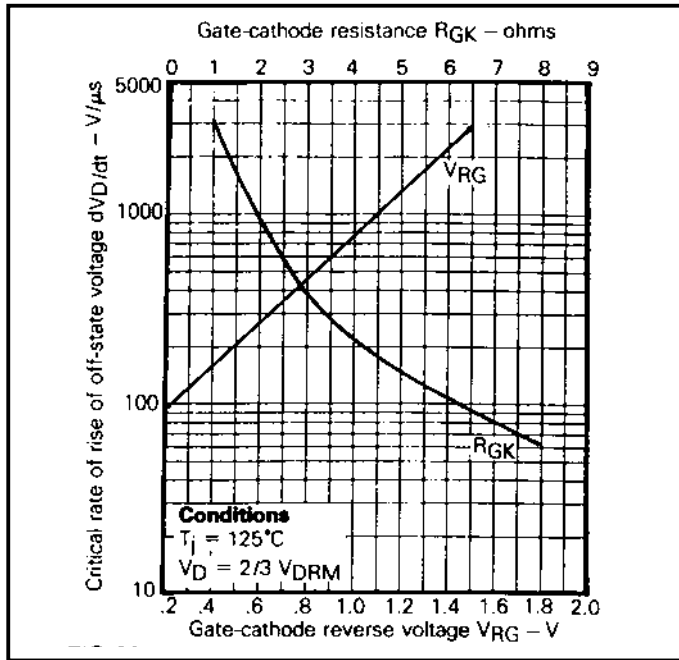


Fig.28 Dependence of critical dV_D/dt on gate-cathode resistance and gate-cathode reverse voltage

Snubber Capacitor C_s (μF)	Snubber Resistor R_s (Ω)	Minimum Reset Time (μs)
2	7	35
	5	30
1.5	7	26
	5	22
1	7	17
	5	15

Table of snubber discharge time variation with snubber capacitor value.

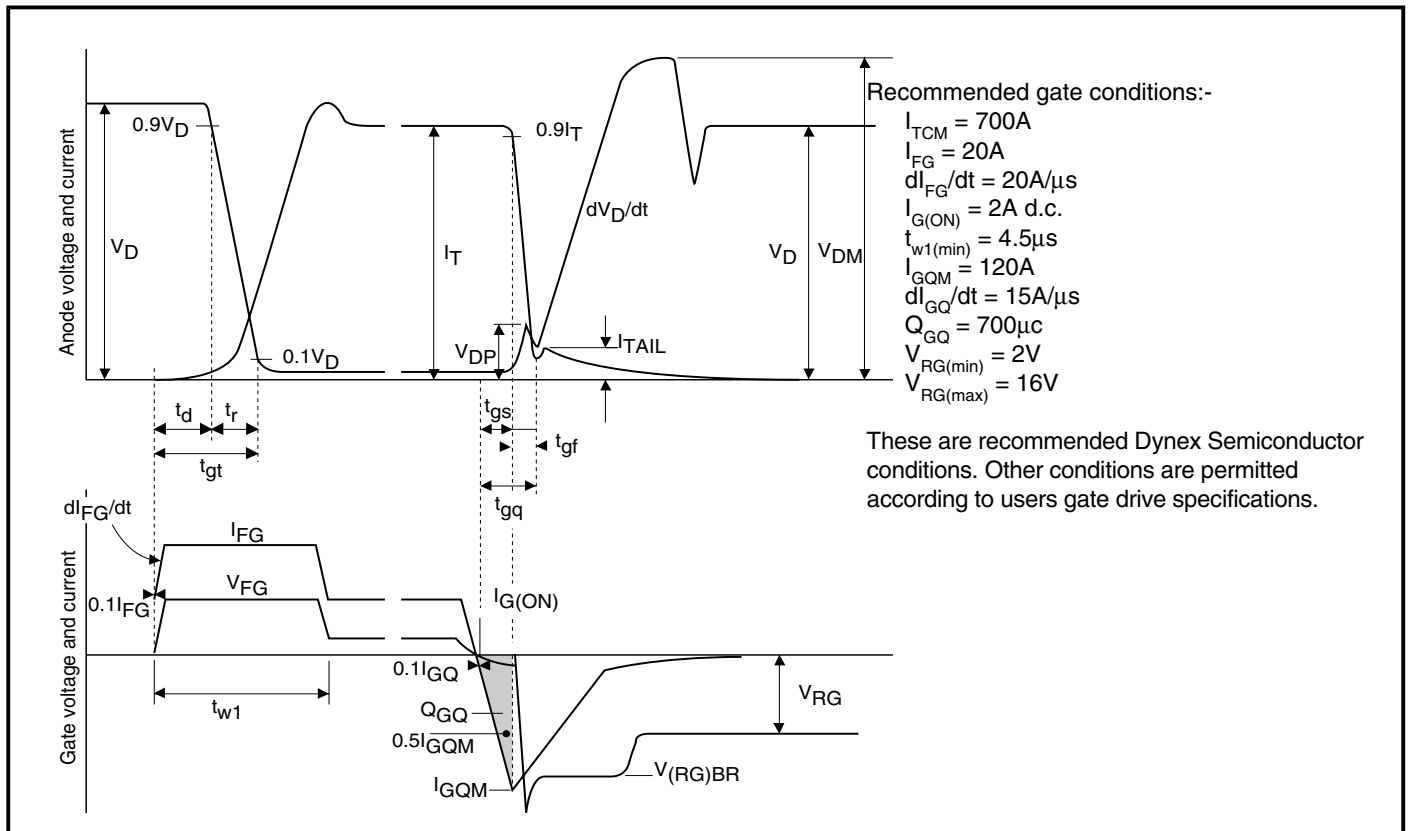
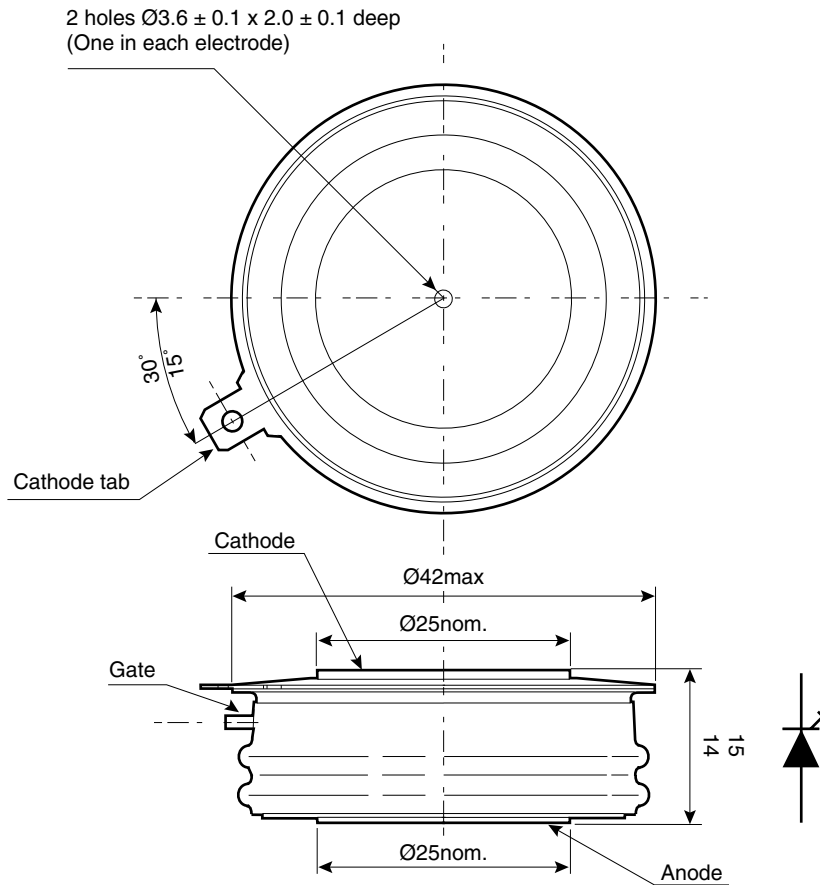


Fig.29 General switching waveforms

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise.
DO NOT SCALE.



Nominal weight: 82g
Clamping force: $6\text{kN} \pm 10\%$
Leads 12AWG cable 160mm long

Package outline type code: E



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Extended exposure to conditions outside the product ratings may affect reliability leading to premature product failure. Use outside the product ratings is likely to cause permanent damage to the product. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture, a large current to flow or high voltage arcing, resulting in fire or explosion. Appropriate application design and safety precautions should always be followed to protect persons and property.

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Preliminary Information:	The product design is complete and final characterisation for volume production is in progress. The datasheet represents the product as it is now understood but details may change.
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